

# **Excellent Integrated System Limited**

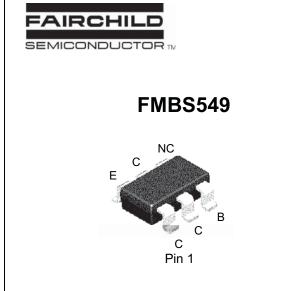
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Fairchild Semiconductor FMBS549

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Package: SuperSOT-6 single Mark : .S1

## **PNP Low Saturation Transistor**

This device is designed with high current gain and low saturation voltage with collector currents up to 2A continous. Sourced from process PB.

Symbol	Parameter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage	30	V
V <sub>СВО</sub>	Collector-Base Voltage	35	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
Ic	Collector Current- Continuous - Peak Pulse Current	1 2	A A
TJ, TSTG	Operating and Storage Junction Temperature Range	-55 to +150	°C

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150°C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

### Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristics	Мах	Units
PD	Total Device Dissipation*	700	mW
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, total	180	°C/W
	*		

\*Device mounted on a 1 in2 pad of 2 oz copper.

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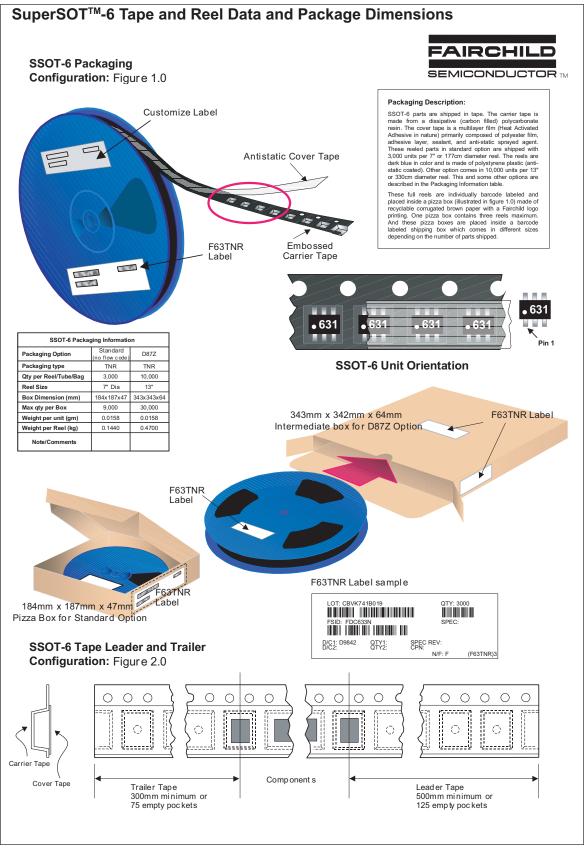


Symbol	Electrical Characteristics TA = 25°C unless otherwise noted							
	Parameter	Test Conditions	Min	Мах	Units			
OFF CHAF	RACTERISTICS							
BV <sub>CEO</sub>	Collector to Emitter Voltage	Ic = 10 mA	30		V			
BV <sub>CBO</sub>	Collector to Base Voltage	Ic = 100 uA	35		V			
BV <sub>EBO</sub>	Emitter to Base Voltage	le = 100 uA	5		V			
I <sub>СВО</sub>	Collector Cutoff Current	Vcb = 30 V Vcb = 30 V, Ta= 100C		100 10	nA uA			
I <sub>EBO</sub>	Emitter Cutoff Current	Veb = 4 V		100	nA			
	ACTERISTICS							
hfe	DC Current Gain	$\begin{array}{llllllllllllllllllllllllllllllllllll$	70 100 80 40 100	300	-			
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage			200 350 500 750	mV mV mV mV			
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	Ic = 1 A, Ib = 100 mA		1.25	V			
V <sub>BE(on)</sub>	Base-Emitter On Voltage	Ic = 1 A, Vce = 2 V		1	V			
SMALL SI	GNAL CHARACTERISTICS							
C <sub>obo</sub>	Output Capacitance	Vcb = 10V, f = 1MHz	25		pF			
f <sub>T</sub>	Current Gain - Bandwidth Product	Vce = 5 V, Ic = 100mA, f = 100MHz	100		MHz			

fmbs549.lwp Rev A PrPB

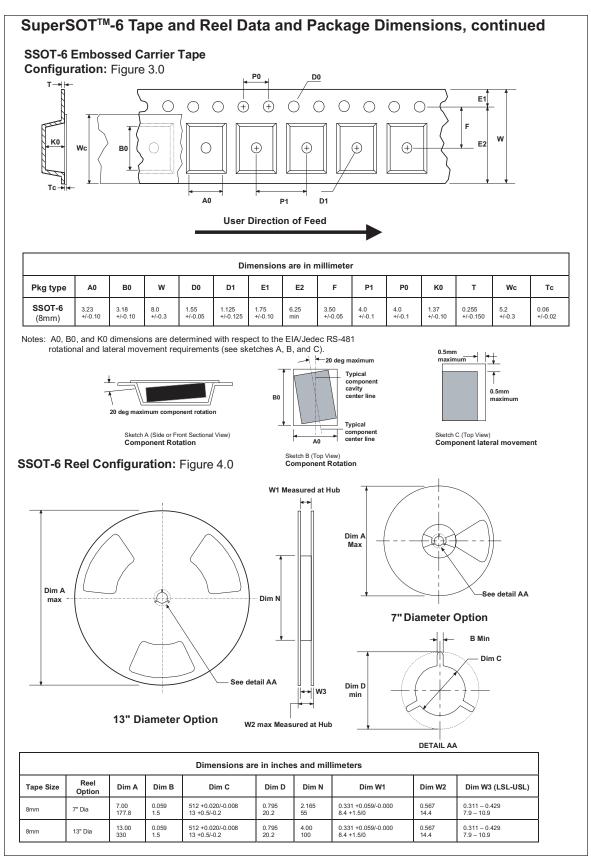
FMBS549





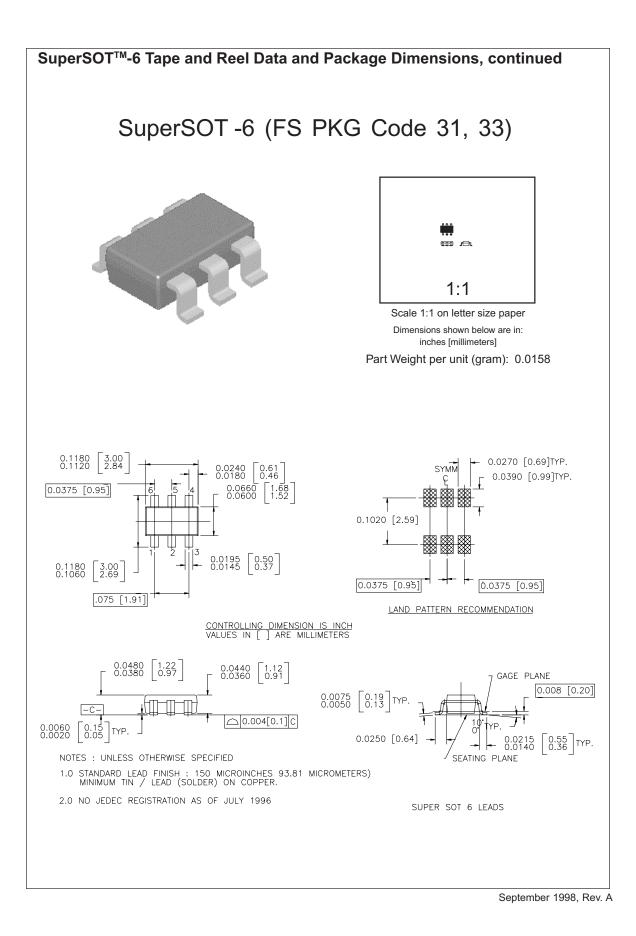
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